

Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (currently amended) A method of generating energy, comprising:
applying a pulse of energy in the vicinity of a reaction surface to start self-sustaining chemical reactions that activate the reaction surface;
stimulating reactions in a region surrounding the reaction surface to create highly vibrationally excited molecules, the chemical reactions sustaining themselves until reactants of the chemical reactions are depleted;
transferring at least some of vibration energy of the highly vibrationally excited molecules to carriers in a conducting surface to form hot carriers in pulses; and
converting energy of the hot carriers highly vibrationally excited molecules created from the stimulated reactions to useful work energy.
2. (canceled)
3. (currently amended) The method of generating energy as claimed in claim 1, further including:
collecting the useful work energy.
4. (original) The method of generating energy as claimed in claim 1, wherein the applying includes applying a pulse of energy with pulse duration shorter than thrice the time it takes for energy vibrations on the reaction surface to equilibrate with its substrate.
5. (original) The method of generating energy as claimed in claim 1, wherein a distance between a reaction surface and a converter of hot electron energy is equal to or less than thrice the aggregate energy diffusion length of electrons generated by the pulse of energy.

6. (previously presented) The method of generating energy as claimed in claim 1, wherein the pulse of energy includes hot electrons, photons, or phonons, or combinations thereof.

7. (original) The method of generating energy as claimed in claim 1, wherein the applying includes applying pulses of energy in intervals, wherein the interval between the pulses is shorter than a time associated with the dissociation of adsorbates.

8. (original) The method of generating energy as claimed in claim 1, wherein the method further includes:

selecting a material reaction surface that has a high sticking coefficient.

9. (original) The method of generating energy as claimed in claim 1, wherein the applying includes applying a pulse of energy in the vicinity of a reaction surface to create reaction initiators in the reaction surface, and the stimulating occurs in response to the reaction initiators in the reaction vicinity of the reaction surface.

10. (original) The method of generating energy as claimed in claim 9, wherein the reaction initiators includes reaction intermediates.

11. (original) The method of generating energy as claimed in claim 9, wherein the reaction initiators include reaction autocatalysts.

12. (original) The method of generating energy as claimed in claim 9, wherein the reaction initiators include translationally hot species.

13. (original) The method of generating energy as claimed in claim 9, wherein the method further includes flooding the reaction surface with reagents.

14. (original) The method of generating energy as claimed in claim 13, wherein the reagents include fuel.

15. (original) The method of generating energy as claimed in claim 9, wherein the reaction initiators are created in pulses with durations less than twenty nanoseconds.

16. (original) The method of generating energy as claimed in claim 1, wherein the stimulating includes stimulating reactions in a region surrounding the reaction surface to create highly vibrationally excited molecules near a converter.

17. (original) The method of generating energy as claimed in claim 16, wherein a distance between the converter and the region where the stimulating occurs is within thrice the diffusion distance of the highly vibrationally excited molecules.

18. (previously presented) The method of generating energy as claimed in claim 1, wherein the method further includes:

allowing exhausts formed from the reactions to leave a collector surface; and generating at least one watt/cm² of power from the reactions.

19. (original) The method of generating energy as claimed in claim 2, wherein the hot electrons are transported as carriers in one of semiconductor and insulator, and cause chemical reactions to create additional hot electrons.

20. (currently amended) A device for generating energy, comprising:
an emitter that stimulates and initiates reactions in pulses, the emitter having a reaction surface;
a reaction region surrounding the emitter; and
a collector near the reaction region,
wherein fuel and oxidizer reacting near the reaction surface causes creation of hot electrons in pulses, and the collector converts kinetic energy of the hot electrons into useful work energy.

21. (original) The device of claim 20, wherein the reaction region includes a surface of the emitter.
22. (original) The device of claim 20, wherein the reaction region includes a surface of the collector.
23. (original) The device of claim 20, wherein the emitter and the collector are on a same surface.
24. (original) The device of claim 20, wherein the emitter and the collector are a same one device.
25. (original) The device of claim 20, wherein the reaction region is formed as a V-channel by the surrounding collector.
26. (original) The device of claim 20, wherein the reaction region is partly enclosed by the surrounding collector.
27. (original) The device of claim 20, wherein the emitter includes:
an insulator;
a first electrode connected to a first side of the insulator; and
a second electrode connected to a second side of the insulator, the second electrode forming the reaction surface,
wherein energy pulses can be applied across the first electrode and the second electrode to stimulate reaction on the reaction surface.
28. (original) The device of claim 27, wherein the insulator has thickness dimension that is less than three times the energy diffusion length of hot electrons traversing the insulator.

29. (original) The device of claim 20, wherein the emitter includes one or more of a forward biased diode, a metal-insulator-metal device, a semiconductor-insulator-metal device, a semiconductor-metal device, an optical device, and a quantum well.

30. (original) The device of claim 20, wherein the device further includes a strip transmission line connected to the emitter for driving energy pulses into the emitter.

31. (original) The device of claim 30, wherein the strip transmission line includes a dielectric material in contact with one or more electrodes.

32. (original) The device of claim 30, wherein the strip transmission line includes a dispersive transmission line designed to compress pulses.

33. (original) The device of claim 20, wherein the reaction surface includes a catalyst.

34. (original) The device of claim 20, wherein the collector includes a reaction surface.

35. (original) The device of claim 20, wherein the emitter includes a semiconductor whose p side is ohmically or almost ohmically attached to the reaction surface.

36. (original) The device of claim 20, wherein the emitter includes an electrically pulsed solid state optically emitting diode.

37. (original) The device for generating energy as claimed in claim 20, wherein the collector includes:

a conductor surface;

a conductor electrode connected to the conductor surface;

a collector semiconductor connected to the conductor surface; and

a collector electrode in contact with the semiconductor,
wherein the hot electrons created in the collector travel via the conductor surface
and the conductor electrode to cause the semiconductor to become forward biased and
produces useful voltage across the collector electrode.

38. (previously presented) The device of claim 20, wherein the collector includes:
a conductor having a surface; and
a semiconductor directly connected to the conductor surface.

39. (original) The device of claim 20, wherein the collector includes:
a conductor having a surface; and
a quantum well structure directly connected to the conductor surface.

40. (original) The device of claim 20, wherein the collector includes:
a conductor having a surface; and
a Schottky diode directly connected to the conductor surface.

41. (original) The device of claim 20, wherein the collector includes a conducting
surface supplied with one or combination of fuel and oxidizer additives.

42. (original) The device of claim 20, wherein the collector includes a conducting
surface with superlattice structures.

43. (original) The device of claim 20, wherein the collector includes a conducting
surface formed from material with a Debye temperature property chosen to optimize the
ratio of hot electrons and phonons generated upon exposure to reaction products.

44. (original) The device of claim 20, wherein the collector collects
electromagnetic radiation.

45. (original) The device of claim 37, wherein the collector semiconductor includes:

- a highly doped p+ region;
- a p doped region; and
- a n doped region.

46. (original) The device of claim 20, wherein the device further includes a fuel port in close proximity to the emitter.

47. (currently amended) A method of extracting a net excess of useful work, comprising:

applying a pulse of energy in the vicinity of a reaction surface to initiate chemical reactions that sustain themselves until reactants of the chemical reactions are depleted, the chemical reactions creating activate the reaction surface;

stimulating reactions in a region surrounding the reaction surface to create highly vibrationally excited molecules;

transferring at least some of vibration energy of the highly vibrationally excited molecules to carriers in a conducting surface to form hot carriers;

repeating the applying and the transferring steps wherein hot carriers are created in pulses; and

converting energy of the hot carriers highly vibrationally excited molecules created from the stimulated reactions to useful work energy.

48. (currently amended) A device for extracting a net excess of useful work, comprising:

an emitter that stimulates and initiates reactions in pulses, the emitter having a reaction surface;

a reaction region near the emitter; and

a collector near the reaction region,

wherein fuel and oxidizer reacting near the reaction surface causes creation of hot electrons in pulses, and the collector converts kinetic energy of the hot electrons into useful work energy.